

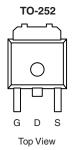
N-Channel 60-V (D-S) MOSFET

| PRODUCT SUMMARY | | | | | |
|---------------------|----------------------------------|---------------------------------|--|--|--|
| V _{DS} (V) | $r_{DS(on)}\left(\Omega\right)$ | I _D (A) ^a | | | |
| 60 | 0.025 at V _{GS} = 10 V | 45 | | | |
| 00 | 0.030 at V _{GS} = 4.5 V | 40 | | | |

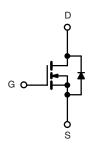
FEATURES

- TrenchFET® Power MOSFET
- 175 °C Junction Temperature





Drain Connected to Tab



N-Channel MOSFET

| ABSOLUTE MAXIMUM RATINGS $T_C = 25$ °C, unless otherwise noted | | | | | |
|---|-------------------------|-----------------------------------|----------------|------|--|
| Parameter | | Symbol | Limit | Unit | |
| Gate-Source Voltage | | V _{GS} | ± 20 | V | |
| Continuous Drain Current (T _{.I} = 175 °C) ^b | T _C = 25 °C | L | 45 | | |
| Continuous Drain Current (1 _J = 175 °C) ² | T _C = 100 °C | I _D | 35 | | |
| Pulsed Drain Current | I _{DM} | 100 | A | | |
| Continuous Source Current (Diode Conduction) | I _S | 23 | 1 | | |
| Avalanche Current | I _{AS} | 20 | | | |
| Single Avalanche Energy (Duty Cycle ≤ 1 %) | L = 0.1 mH | E _{AS} | 20 | mJ | |
| Maximum Daway Dissination | T _C = 25 °C | D ₋ | 100 | 14/ | |
| Maximum Power Dissipation | T _A = 25 °C | P _D | 3 ^a | W | |
| Operating Junction and Storage Temperature Range | | T _J , T _{stg} | - 55 to 175 | °C | |

| THERMAL RESISTANCE RATINGS | | | | | | | |
|--|--------------|---------------------|---------|---------|------|--|--|
| Parameter | | Symbol | Typical | Maximum | Unit | | |
| Maximum Junction-to-Ambient ^a | t ≤ 10 sec | - R _{thJA} | 18 | 22 | °C/W | | |
| Maximum Junction-to-Ambient | Steady State | | 40 | 50 | | | |
| Maximum Junction-to-Case | | R _{thJC} | 3.2 | 4 | | | |

Notes:

a. Surface Mounted on 1" x 1" FR4 board, $t \le 10$ sec.

服务热线:400-655-8788



| Symbol | Test Conditions | | SPECIFICATIONS $T_J = 25$ °C, unless otherwise noted Parameter Symbol Test Conditions Min Typa Max Unit | | | | | | | |
|---------------------|---|---|---|---|---|--|--|--|--|--|
| | rest conditions | Min | Typ ^a | Max | Unit | | | | | |
| | | | 1 | T | | | | | | |
| | $V_{(BR)DSS}$ $V_{GS} = 0 \text{ V, I}_{D} = 250 \mu\text{A}$ 60 | | | | V | | | | | |
| V _{GS(th)} | | 1.0 | 2.0 | 3.0 | | | | | | |
| I _{GSS} | | | | ± 100 | nA | | | | | |
| | 20 60 | | | 1 | | | | | | |
| I _{DSS} | | | | 50 | μΑ | | | | | |
| | $V_{DS} = 60 \text{ V}, V_{GS} = 0 \text{ V}, T_{J} = 175 ^{\circ}\text{C}$ | | | 250 | | | | | | |
| I _{D(on)} | $V_{DS} = 5 \text{ V}, V_{GS} = 10 \text{ V}$ | 50 | | | Α | | | | | |
| | V _{GS} = 10 V, I _D = 15 A | | 0.025 | | | | | | | |
| _ | $V_{GS} = 10 \text{ V}, I_D = 15 \text{ A}, T_J = 125 ^{\circ}\text{C}$ | | 0.055 | | Ω | | | | | |
| ¹ DS(on) | V _{GS} = 10 V, I _D = 15 A, T _J = 175 °C | | 0.069 | | | | | | | |
| | $V_{GS} = 4.5 \text{ V}, I_D = 10 \text{ A}$ | | 0.030 | | | | | | | |
| 9 _{fs} | V _{DS} = 15 V, I _D = 15 A | | 20 | | S | | | | | |
| | | | | | | | | | | |
| C _{iss} | | | 1500 | | pF | | | | | |
| C _{oss} | $V_{GS} = 0 \text{ V}, V_{DS} = 25 \text{ V}, f = 1 \text{ MHz}$ | | 140 | | | | | | | |
| C _{rss} | | | 60 | | 1 | | | | | |
| Q_g | | | 11 | 17 | | | | | | |
| Q_{gs} | $V_{DS} = 30 \text{ V}, V_{GS} = 10 \text{ V}, I_D = 23 \text{ A}$ | | 3 | | nC | | | | | |
| Q_{gd} | | | 3 | | 1 | | | | | |
| t _{d(on)} | | | 8 | 15 | | | | | | |
| t _r | V_{DD} = 30 V, R_L = 1.3 Ω | | 15 | 25 | | | | | | |
| t _{d(off)} | $I_D\cong 23$ A, V_{GEN} = 10 V, R_g = 2.5 Ω | | 30 | 45 | ns | | | | | |
| t _f | | | 25 | 40 | | | | | | |
| aracteristics | (T _C = 25 °C) | | • | | | | | | | |
| I _{SM} | | | | 50 | Α | | | | | |
| V_{SD} | I _F = 15 A, V _{GS} = 0 V | | 1.0 | 1.5 | V | | | | | |
| t _{rr} | I _F = 15 A, di/dt = 100 A/μs | | 30 | 60 | ns | | | | | |
| | V _{GS(th)} I _{GSS} I _{DSS} I _{D(on)} I _{D(on} | $\begin{array}{c ccccc} V_{GS(th)} & V_{DS} = V_{GS}, \ I_D = 250 \ \mu A \\ \hline V_{DS} = 0 \ V, \ V_{GS} = \pm 20 \ V \\ \hline V_{DS} = 60 \ V, \ V_{GS} = 0 \ V \\ \hline V_{DS} = 60 \ V, \ V_{GS} = 0 \ V, \ T_J = 125 \ ^{\circ}C \\ \hline V_{DS} = 60 \ V, \ V_{GS} = 0 \ V, \ T_J = 125 \ ^{\circ}C \\ \hline V_{DS} = 60 \ V, \ V_{GS} = 0 \ V, \ T_J = 175 \ ^{\circ}C \\ \hline V_{DS} = 5 \ V, \ V_{GS} = 10 \ V \\ \hline V_{DS} = 5 \ V, \ V_{GS} = 10 \ V \\ \hline V_{GS} = 10 \ V, \ I_D = 15 \ A, \ T_J = 125 \ ^{\circ}C \\ \hline V_{GS} = 10 \ V, \ I_D = 15 \ A, \ T_J = 125 \ ^{\circ}C \\ \hline V_{GS} = 10 \ V, \ I_D = 15 \ A, \ T_J = 175 \ ^{\circ}C \\ \hline V_{GS} = 4.5 \ V, \ I_D = 10 \ A \\ \hline V_{DS} = 15 \ V, \ I_D = 15 \ A \\ \hline C_{ISS} \\ \hline C_{OSS} \\ \hline C_{OSS} \\ \hline C_{OSS} \\ \hline C_{Qg} \\ \hline Q_{Qg} \\ \hline V_{DS} = 30 \ V, \ V_{GS} = 10 \ V, \ I_D = 23 \ A \\ \hline V_{DD} = 30 \ V, \ R_L = 1.3 \ \Omega \\ \hline I_D \cong 23 \ A, \ V_{GEN} = 10 \ V, \ R_g = 2.5 \ \Omega \\ \hline I_{SM} \\ \hline V_{SD} \\ \hline \end{array}$ | $\begin{array}{c ccccccccccccccccccccccccccccccccccc$ | $\begin{array}{c ccccccccccccccccccccccccccccccccccc$ | $\begin{array}{c ccccccccccccccccccccccccccccccccccc$ | | | | | |

Notes:

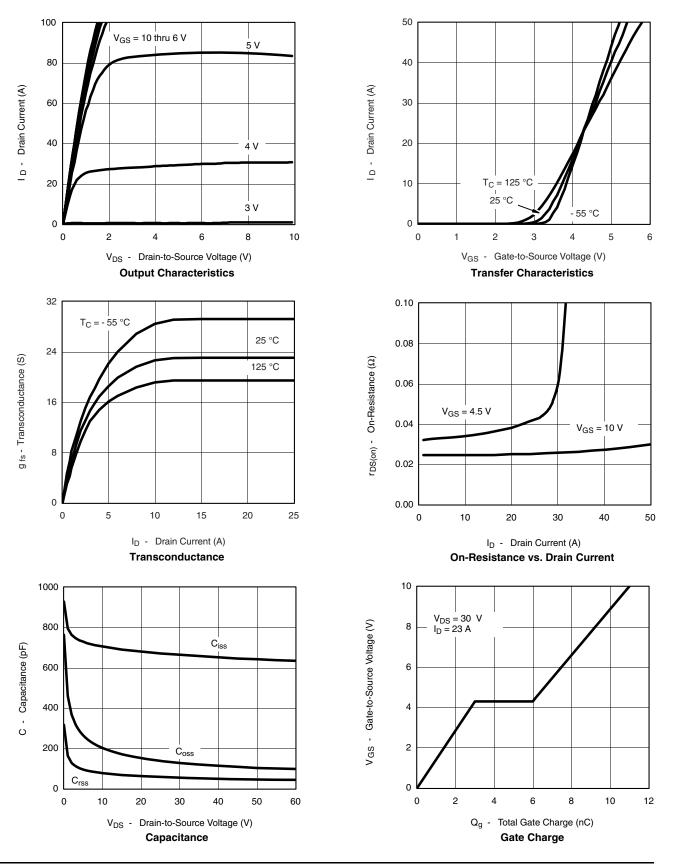
- a. For design aid only; not subject to production testing.
- b. Pulse test; pulse width $\leq 300~\mu s,$ duty cycle $\leq 2~\%.$
- c. Independent of operating temperature.

Stresses beyond those listed under "Absolute Maximum Ratings" may cause permanent damage to the device. These are stress ratings only, and functional operation of the device at these or any other conditions beyond those indicated in the operational sections of the specifications is not implied. Exposure to absolute maximum rating conditions for extended periods may affect device reliability.

服务热线:400-655-8788

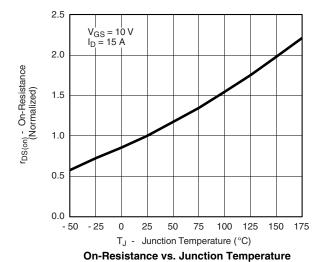


TYPICAL CHARACTERISTICS 25 °C unless noted





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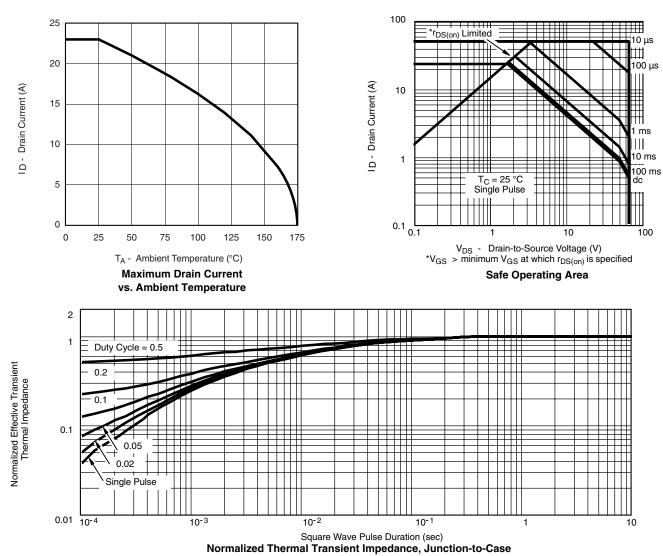
T_J = 150 °C T_J = 25 °C T_J

100

Source-Drain Diode Forward Voltage

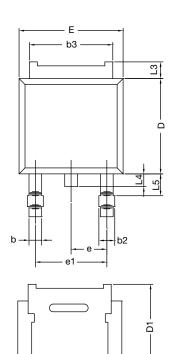


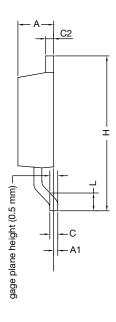
THERMAL RATINGS





TO-252AA CASE OUTLINE





| | MILLIMETERS | | INC | HES | |
|---------------------------------|-------------|-------|-----------|-------|--|
| DIM. | MIN. | MAX. | MIN. | MAX. | |
| Α | 2.18 | 2.38 | 0.086 | 0.094 | |
| A1 | - | 0.127 | - | 0.005 | |
| b | 0.64 | 0.88 | 0.025 | 0.035 | |
| b2 | 0.76 | 1.14 | 0.030 | 0.045 | |
| b3 | 4.95 | 5.46 | 0.195 | 0.215 | |
| С | 0.46 | 0.61 | 0.018 | 0.024 | |
| C2 | 0.46 | 0.89 | 0.018 | 0.035 | |
| D | 5.97 | 6.22 | 0.235 | 0.245 | |
| D1 | 5.21 | - | 0.205 | - | |
| Е | 6.35 | 6.73 | 0.250 | 0.265 | |
| E1 | 4.32 | - | 0.170 | - | |
| Н | 9.40 | 10.41 | 0.370 | 0.410 | |
| е | 2.28 | BSC | 0.090 BSC | | |
| e1 | 4.56 BSC | | 0.180 BSC | | |
| L | 1.40 | 1.78 | 0.055 | 0.070 | |
| L3 | 0.89 | 1.27 | 0.035 | 0.050 | |
| L4 | - | 1.02 | - | 0.040 | |
| L5 | 1.14 | 1.52 | 0.045 | 0.060 | |
| ECN: X12-0247-Rev. M, 24-Dec-12 | | | | | |

ECN: X12-0247-Rev. M, 24-Dec-12

DWG: 5347

Note

• Dimension L3 is for reference only.



RECOMMENDED MINIMUM PADS FOR DPAK (TO-252)



Recommended Minimum Pads Dimensions in Inches/(mm)



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